

## HD34385

# **MEMS Band Pass Filter**

### Features:

■ Pass Band : 10.0G~ 14.0GHz ■ Insertion Loss : 2.0dB ■ Size : 11.7x4.0x0.5mm

### **Absolute Maximum Ratings**

■ Max. Input Power: +35dBm

■ Storage Temperature : -55 ~ +85Deg.C ■ Operating Temperature : -55 ~ +125Deg.C



### Electrical Specifications (T<sub>A</sub>=+25Deg.C, 50Ω system)

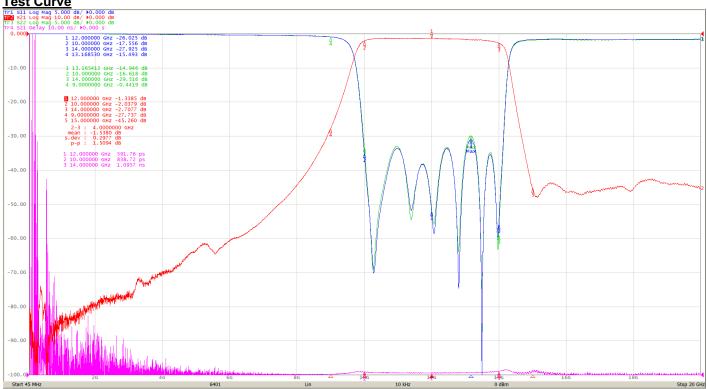
Parameter		Min.Value	Typical Value	Max.Value	Unit
Frequency Range		10.0 ~ 14.0			GHz
Insertion Loss (Fc)		-	1.33	2.0	dB
Ripple		-	1.50	2.0	dB
Attenuation	DC~@9GHz	20.0	27.73	-	dB
	@15.0GHz	40.0	45.26	-	dB
Return Loss		14.0	14.94	-	dB
Group Delay		-	1.21	2.5	ns



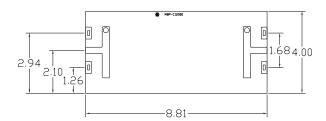
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### **Test Curve**



### <u>Size</u>



Remarks:Unit: mm, Tolerance: ±0.25mm

- 1. Chip bottom is gold plated and grounded.
- 2. Bonding pressure points are gold plated.
- 3. Don't bond on the through holes.

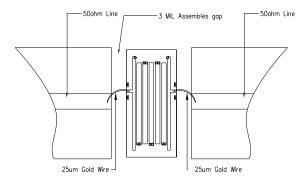


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### **Applications**

1. Assembly and Bonding Diagram. (Reference)



**Assembly Diagram** 

- 2. The chip is back-metalized and can be die mounted with AuSn eutectic performs or with electrically conductive epoxy (for example ME8456).
- 3. The die should be assembled on carriers like Kovar or Mu-Cu which have same Coefficient of thermal expansion. (2.9ppm/°C) with Silicon, thickness 0.2mm max.
- 4. Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.
- 5. Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers.